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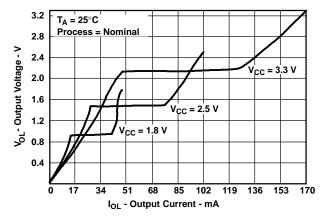
#### **FEATURES**

- Member of the Texas Instruments Widebus™
   Family
- EPIC™ (Enhanced-Performance Implanted CMOS) Submicron Process
- DOC™ (Dynamic Output Control) Circuit Dynamically Changes Output Impedance, Resulting in Noise Reduction Without Speed Degradation
- Dynamic Drive Capability Is Equivalent to Standard Outputs With I $_{OH}$  and I $_{OL}$  of  $\pm$ 24 mA at 2.5-V V $_{CC}$

- Overvoltage-Tolerant Inputs/Outputs Allow Mixed-Voltage-Mode Data Communications
- I<sub>off</sub> Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- Package Options Include Plastic Thin Shrink Small-Outline (DGG) and Thin Very Small-Outline (DGV) Packages

### **DESCRIPTION**

A Dynamic Output Control (DOC<sup>TM</sup>) circuit is implemented, which, during the transition, initially lowers the output impedance to effectively drive the load and, subsequently, raises the impedance to reduce noise. Figure 1 shows typical  $V_{OL}$  vs  $I_{OL}$  and  $V_{OH}$  vs  $I_{OH}$  curves to illustrate the output impedance and drive capability of the circuit. At the beginning of the signal transition, the DOC circuit provides a maximum dynamic drive that is equivalent to a high-drive standard-output device. For more information, refer to the TI application reports, *AVC Logic Family Technology and Applications*, literature number SCEA006, and *Dynamic Output Control (DOC*<sup>TM</sup>) *Circuitry Technology and Applications*, literature number SCEA009.



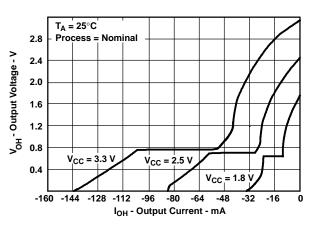


Figure 1. Output Voltage vs Output Current

This 16-bit bus transceiver and register is operational at 1.2-V to 3.6-V  $V_{CC}$ , but is designed specifically for 1.65-V to 3.6-V  $V_{CC}$  operation.

The SN74AVC16646 can be used as two 8-bit transceivers or one 16-bit transceiver. Data on the A or B bus is clocked into the registers on the low-to-high transition of the appropriate clock (CLKAB or CLKBA) input. Figure 2 illustrates the four fundamental bus-management functions that can be performed with the SN74AVC16646.

Output-enable ( $\overline{\text{OE}}$ ) and direction-control (DIR) inputs are provided to control the transceiver functions. In the transceiver mode, data present at the high-impedance port may be stored in either register or in both. The select-control (SAB and SBA) inputs can multiplex stored and real-time (transparent mode) data.



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## **DESCRIPTION (CONTINUED)**

The circuitry used for select control eliminates the typical decoding glitch that occurs in a multiplexer during the transition between stored and real-time data. DIR determines which bus receives data when  $\overline{OE}$  is low. In the isolation mode ( $\overline{OE}$  high), A data may be stored in one register and/or B data may be stored in the other register.

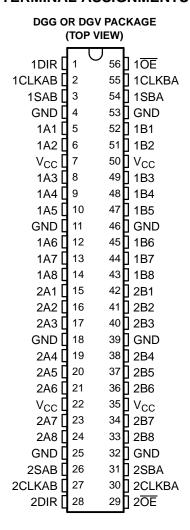
When an output function is disabled, the input function still is enabled and may be used to store and transmit data. Only one of the two buses, A or B, can be driven at a time.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

This device is fully specified for partial-power-down applications using  $I_{\text{off}}$ . The  $I_{\text{off}}$  circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

The SN74AVC16646 is characterized for operation from -40°C to 85°C.

#### **TERMINAL ASSIGNMENTS**





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# FUNCTION TABLE (EACH 8-BIT TRANSCEIVER/REGISTER)

		INP	UTS			DATA	A I/Os	ODED A TION OD FUNCTION
ŌĒ	DIR	CLKAB	CLKBA	SAB	SBA	A1-A8	B1-B8	OPERATION OR FUNCTION
Х	Х	1	Х	Х	Х	Input	Unspecified <sup>(1)</sup>	Store A, B unspecified <sup>(1)</sup>
X	X	Χ	$\uparrow$	Χ	Χ	Unspecified <sup>(1)</sup>	Input	Store B, A unspecified (1)
Н	Х	1	1	Х	Х	Input	Input	Store A and B data
Н	X	H or L	H or L	Χ	Χ	Input disabled	Input disabled	Isolation, hold storage
L	L	Х	Х	Х	L	Output	Input	Real-time B data to A bus
L	L	Χ	H or L	Χ	Н	Output	Input	Stored B data to A bus
L	Н	Х	Х	L	Х	Input	Output	Real-time A data to B bus
L	Н	H or L	Χ	Н	X	Input	Output	Stored A data to B bus

<sup>(1)</sup> The data-output functions may be enabled or disabled by various signals at OE and DIR. Data-input functions always are enabled; i.e., data at the bus terminals is stored on every low-to-high transition of the clock inputs.



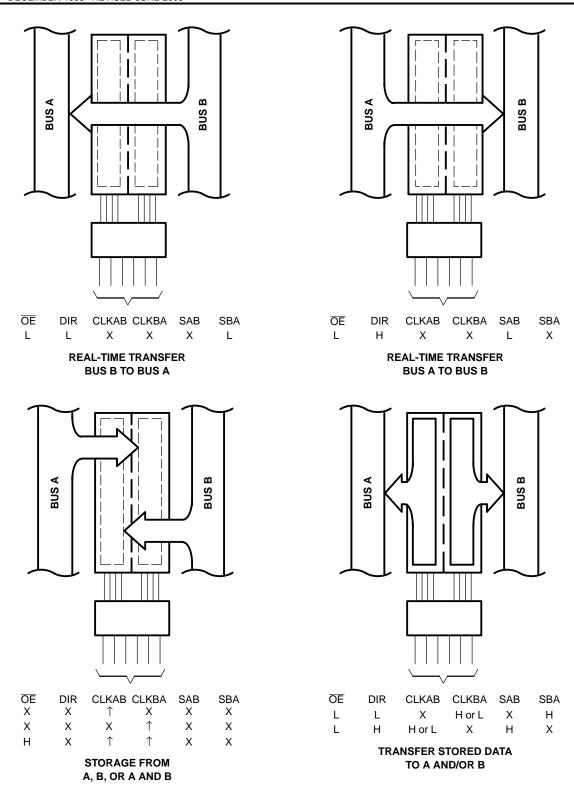
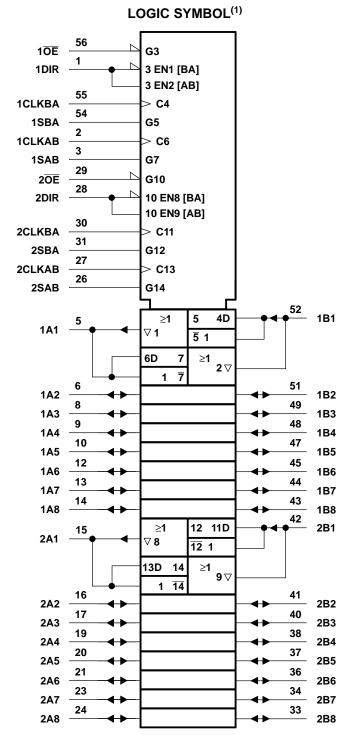


Figure 2. Bus-Management Functions



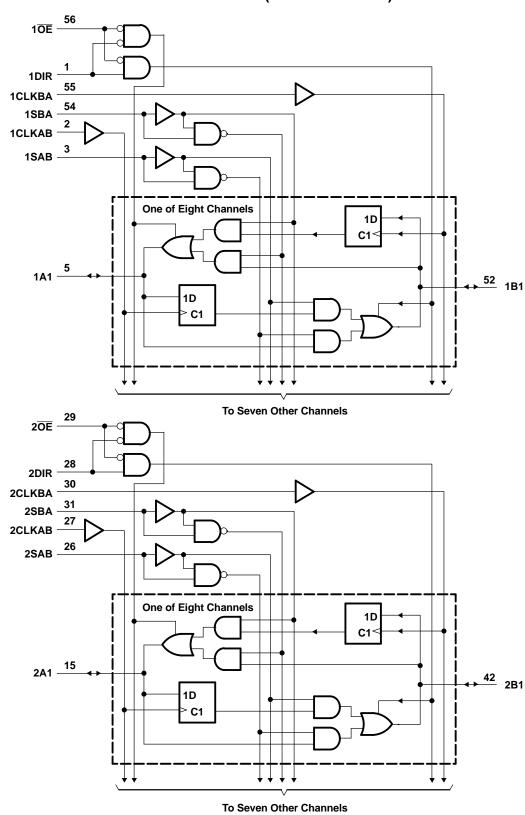




(1) This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.



## **LOGIC DIAGRAM (POSITIVE LOGIC)**





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# Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
$V_{CC}$	Supply voltage range		-0.5	4.6	V
VI	Input voltage range <sup>(2)</sup>		-0.5	4.6	V
Vo	Voltage range applied to any input/output when the output is in the high-impedance or pow	er-off state <sup>(2)</sup>	-0.5	4.6	V
Vo	Voltage range applied to any input/output when t	he output is in the high or low state (2)(3)	-0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	Input clamp current	V <sub>I</sub> < 0		-50	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		-50	mA
Io	Continuous output current			±50	mA
	Continuous current through each V <sub>CC</sub> or GND			±100	mA
0	Deckage thermal impedance (4)	DGG package		64	°C/W
$\theta_{JA}$	Package thermal impedance <sup>(4)</sup>	DGV package		48	· C/VV
T <sub>stg</sub>	Storage temperature range		-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

The output positive-voltage rating may be exceeded up to 4.6 V maximum if the output current rating is observed.

The package thermal impedance is calculated in accordance with JESD 51.





# Recommended Operating Conditions<sup>(1)</sup>

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage	Operating	1.2	3.6	V
		V <sub>CC</sub> = 1.2 V	V <sub>CC</sub>		
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	0.65 × V <sub>CC</sub>		
$V_{IH}$	High-level input voltage	$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	0.65 × V <sub>CC</sub>		V
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7		
		V <sub>CC</sub> = 3 V to 3.6 V	2		
		V <sub>CC</sub> = 1.2 V		GND	
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$		$0.35 \times V_{CC}$	
$V_{IL}$	Low-level input voltage	$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		$0.35 \times V_{CC}$	V
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7	
		V <sub>CC</sub> = 3 V to 3.6 V		0.8	
VI	Input voltage		0	3.6	V
V	Output voltage	Active state	0	V <sub>CC</sub>	V
V <sub>O</sub>	Output voltage	3-state	0	3.6	V
		V <sub>CC</sub> = 1.4 V to 1.6 V		-2	
	Static high layed output ourrent(2)	$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		-4	A
I <sub>OHS</sub>	Static high-level output current (2)	V <sub>CC</sub> = 2.3 V to 2.7 V		-8	mA
		V <sub>CC</sub> = 3 V to 3.6 V		-12	
		V <sub>CC</sub> = 1.4 V to 1.6 V		2	
	Static law level output ourrent(2)	$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		4	A
I <sub>OLS</sub>	Static low-level output current <sup>(2)</sup>	V <sub>CC</sub> = 2.3 V to 2.7 V		8	mA
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$		12	
Δt/Δν	Input transition rise or fall rate	V <sub>CC</sub> = 1.4 V to 3.6 V		5	ns/V
T <sub>A</sub>	Operating free-air temperature		-40	85	°C

All unused inputs of the device must be held at  $V_{CC}$  or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004. Dynamic drive capability is equivalent to standard outputs with  $I_{OH}$  and  $I_{OL}$  of  $\pm 24$  mA at 3.3-V  $V_{CC}$ . See Figure 1 for  $V_{OL}$  vs  $I_{OL}$  and  $V_{OH}$  vs  $I_{OH}$  characteristics. Refer to the TI application reports, *AVC Logic Family Technology and Applications*, literature number SCEA006, and *Dynamic Output Control (DOC*<sup>TM</sup>) *Circuitry Technology and Applications*, literature number SCEA009.



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## **Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

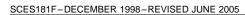
	PARAMETER	TEST CO	NDITIONS	V <sub>CC</sub>	MIN	TYP <sup>(1)</sup>	MAX	UNIT
		$I_{OHS} = -100 \mu A$		1.2 V to 3.6 V	$V_{CC} - 0.2$			
		$I_{OHS} = -2 \text{ mA},$	V <sub>IH</sub> = 0.91 V	1.4 V	1.05			
$V_{OH}$		$I_{OHS} = -4 \text{ mA},$	V <sub>IH</sub> = 1.07 V	1.65 V	1.2			V
		$I_{OHS} = -8 \text{ mA},$	V <sub>IH</sub> = 1.7 V	2.3 V	1.75			
		$I_{OHS} = -12 \text{ mA},$	$V_{IH} = 2 V$	3 V	2.3			
		I <sub>OLS</sub> = 100 μA		1.2 V to 3.6 V			0.2	
		$I_{OLS} = 2 \text{ mA},$	V <sub>IL</sub> = 0.49 V	1.4 V			0.4	
$V_{OL}$		$I_{OLS} = 4 \text{ mA},$	V <sub>IL</sub> = 0.57 V	1.65 V			0.45	V
		$I_{OLS} = 8 \text{ mA},$	$V_{IL} = 0.7 V$	2.3 V			0.55	
		$I_{OLS} = 12 \text{ mA},$	$V_{IL} = 0.8 \ V$	3 V			0.7	
I	Control inputs	$V_I = V_{CC}$ or GND		3.6 V			±2.5	μΑ
I <sub>off</sub>		$V_I$ or $V_O = 3.6 \text{ V}$		0			±10	μΑ
I <sub>OZ</sub> <sup>(2)</sup>		$V_O = V_{CC}$ or GND,	$V_I = V_{CC}$	3.6 V			±12.5	μΑ
$I_{CC}$		$V_I = V_{CC}$ or GND,	$I_O = 0$	3.6 V			40	μΑ
	CLK inputs			2.5 V		3		
_	CLK inputs	V V or CND		3.3 V		3		~F
Ci	Control inputs	$V_I = V_{CC}$ or GND		2.5 V		3.5		pF
	Control inputs			3.3 V		3.5		
C	A or P porto	V - V or CND		2.5 V		8		n.E
C <sub>io</sub>	A or B ports	$V_O = V_{CC}$ or GND		3.3 V		8		pF

## **Timing Requirements**

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3 through Figure 6)

			V <sub>CC</sub> =	: 1.2 V	V <sub>CC</sub> = 1.5 V ± 0.1 V		V <sub>CC</sub> = 1.8 V ± 0.15 V		V <sub>CC</sub> = 2.5 V ± 0.2 V		V <sub>CC</sub> = 3.3 V ± 0.3 V		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f <sub>clock</sub>	Clock freque	ncy						150		250		350	MHz
t <sub>w</sub>	Pulse duration	CLKAB or CLKBA high or low					3.3		2		1.4		ns
t <sub>su</sub>	Setup time	A before CLKAB↑ or B before CLKBA↑	2.1		1.6		1.2		0.9		0.8		ns
t <sub>h</sub>	Hold time	A after CLKAB↑ or B after CLKBA↑	1.3		1		0.8		0.6		0.6		ns

Typical values are measured at  $T_A$  = 25°C. For I/O ports, the parameter I<sub>OZ</sub> includes the input leakage current.





## **Switching Characteristics**

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3 through Figure 6)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 1.2 V	V <sub>CC</sub> = ± 0.		V <sub>CC</sub> = ± 0.1		V <sub>CC</sub> = ± 0.2		V <sub>CC</sub> = :		UNIT
	(INPOT)	(0011 01)	TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f <sub>max</sub>						150		250		350		MHz
	A or B	B or A	4.2	1.6	4.8	1.5	4.3	1.2	3.1	0.9	2.6	
t <sub>pd</sub>	CLKAB or CLKBA	A or B	5.9	2.2	7.4	1.9	6.1	1.3	4	1	3.3	ns
	SAB or SBA		8.2	2.6	10	2.4	6.3	1.8	5.1	1.5	4	
t <sub>en</sub>	ŌĒ	A or B	6.5	2.2	8	1.9	7	1.4	4.6	1.1	4	ns
t <sub>dis</sub>	ŌĒ	A or B	6.7	2.6	8	2.6	7.2	1.4	4.3	1.4	4.2	ns
t <sub>en</sub>	DIR	A or B	6.9	2.2	8.7	1.9	7.4	1.4	5	1.1	4.3	ns
t <sub>dis</sub>	DIR	A or B	7.5	2.6	8.7	2.6	7.6	1.4	4.5	1.4	4.3	ns

# **Operating Characteristics**

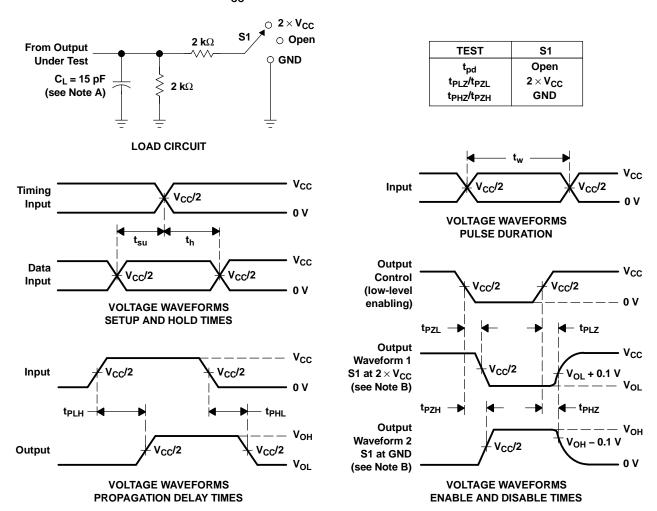
 $T_A = 25^{\circ}C$ 

	PARAMETER		TEST CONDITIONS	V <sub>CC</sub> = 1.8 V	$V_{CC} = 2.5 V$	$V_{CC} = 3.3 \text{ V}$	UNIT
	FARAMETER		TEST CONDITIONS	TYP	TYP	TYP	ONII
_	Dawar dissination conscitones	Outputs enabled	$C_1 = 0$ . $f = 10 \text{ MHz}$	62	73	120	۰
Cpc	Power dissipation capacitance	Outputs disabled	$C_L = 0$ , $f = 10 \text{ MHz}$	25	29	34	pF





# PARAMETER MEASUREMENT INFORMATION $V_{CC} = 1.2 \text{ V}$ AND 1.5 V $\pm$ 0.1 V

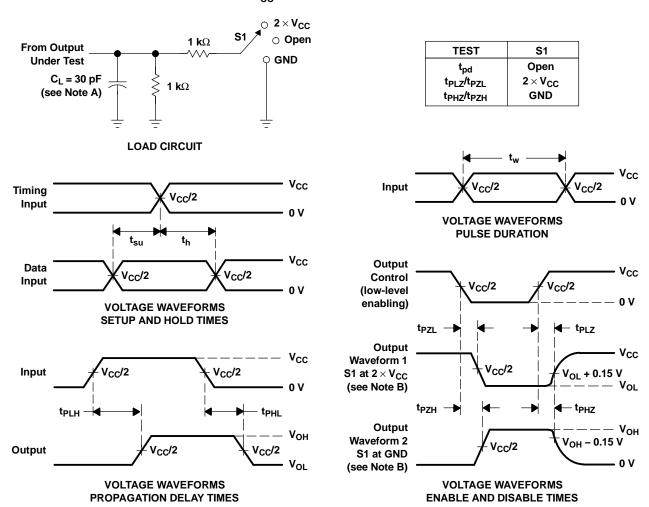


- NOTES: A. C<sub>L</sub> includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O$  = 50  $\Omega$ ,  $t_r \leq$  2 ns.
  - D. The outputs are measured one at a time, with one transition per measurement.
  - E. t<sub>PLZ</sub> and t<sub>PHZ</sub> are the same as t<sub>dis</sub>.
  - F. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.
  - G. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>pd</sub>.

Figure 3. Load Circuit and Voltage Waveforms

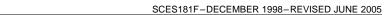


# PARAMETER MEASUREMENT INFORMATION $V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}$



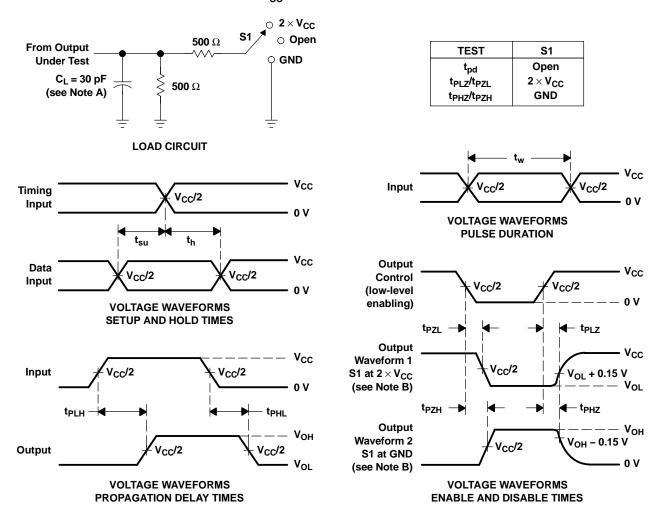
- NOTES: A. C<sub>L</sub> includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ ,  $t_r \leq 2$  ns,  $t_f \leq 2$  ns.
  - D. The outputs are measured one at a time, with one transition per measurement.
  - E. t<sub>PLZ</sub> and t<sub>PHZ</sub> are the same as t<sub>dis</sub>.
  - F. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.
  - G. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>pd</sub>.

Figure 4. Load Circuit and Voltage Waveforms





# PARAMETER MEASUREMENT INFORMATION $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$



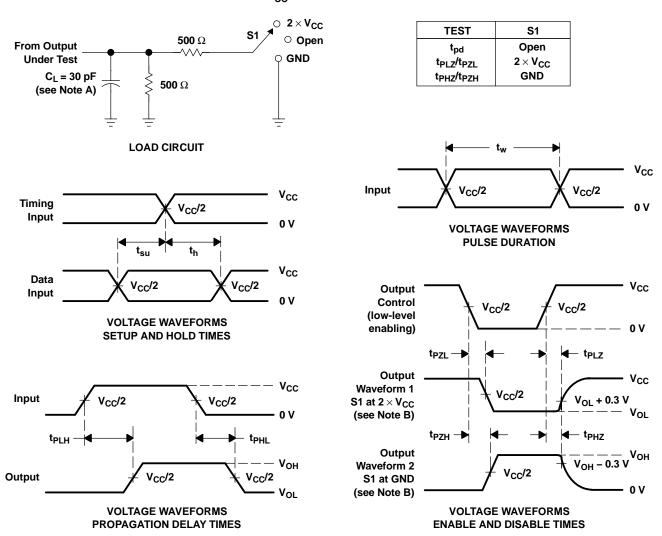
NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ ,  $t_r \leq 2$  ns,  $t_f \leq 2$  ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t<sub>PLZ</sub> and t<sub>PHZ</sub> are the same as t<sub>dis</sub>.
- F. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.
- G. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>pd</sub>.

Figure 5. Load Circuit and Voltage Waveforms



# PARAMETER MEASUREMENT INFORMATION $V_{cc} = 3.3 \text{ V} \pm 0.3 \text{ V}$



- NOTES: A. C<sub>L</sub> includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ ,  $t_f \leq$  2 ns.
  - D. The outputs are measured one at a time, with one transition per measurement.
  - E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - F. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.
  - G. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>pd</sub>.

Figure 6. Load Circuit and Voltage Waveforms

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#### PACKAGING INFORMATION

Orderable part number	Status (1)	Material type	Package   Pins	Package qty   Carrier	<b>RoHS</b> (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
SN74AVC16646DGVR	Active	Production	TVSOP (DGV)   56	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CVA646
SN74AVC16646DGVR.B	Active	Production	TVSOP (DGV)   56	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CVA646

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

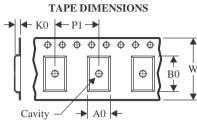
<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

# **PACKAGE MATERIALS INFORMATION**

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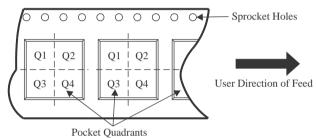
## TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AVC16646DGVR	TVSOP	DGV	56	2000	330.0	24.4	6.8	11.7	1.6	12.0	24.0	Q1

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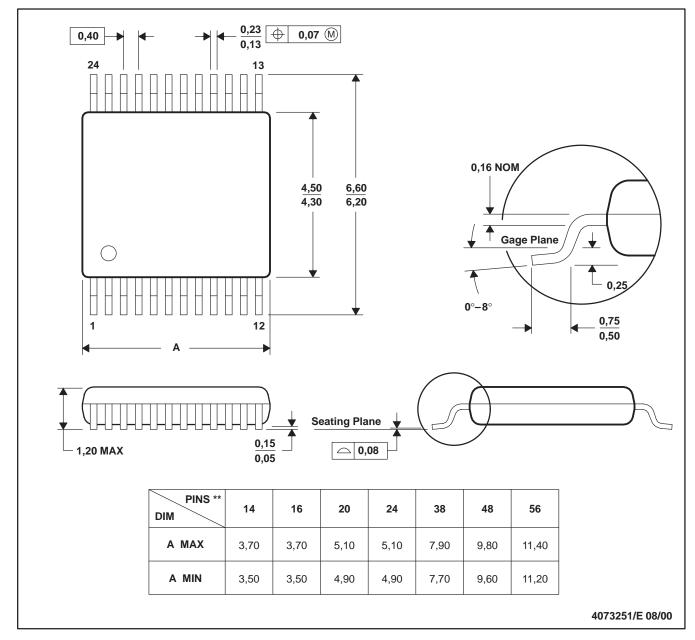
### \*All dimensions are nominal

Ì	Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
ı	SN74AVC16646DGVR	TVSOP	DGV	56	2000	356.0	356.0	45.0

## DGV (R-PDSO-G\*\*)

## 24 PINS SHOWN

#### **PLASTIC SMALL-OUTLINE**



NOTES: A. All linear dimensions are in millimeters.

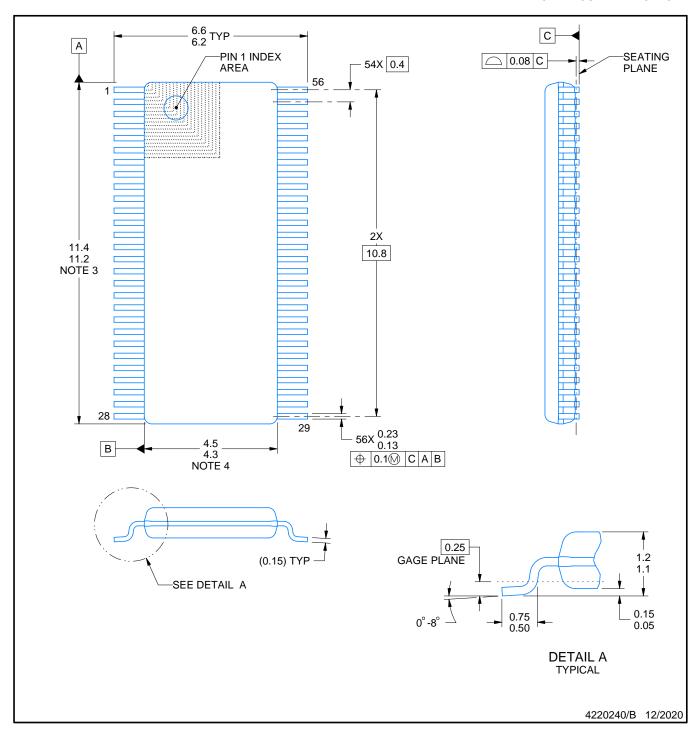
B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194



SMALL OUTLINE PACKAGE



### NOTES:

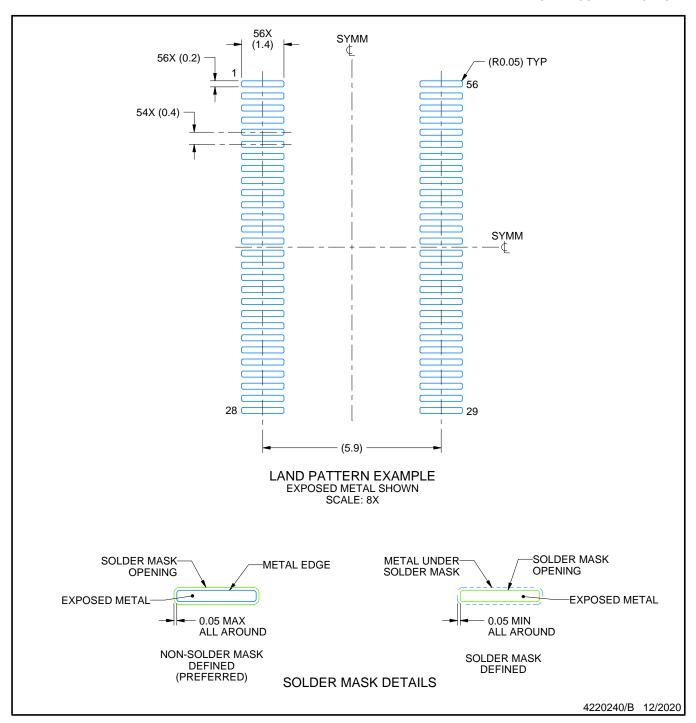
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-194.



SMALL OUTLINE PACKAGE



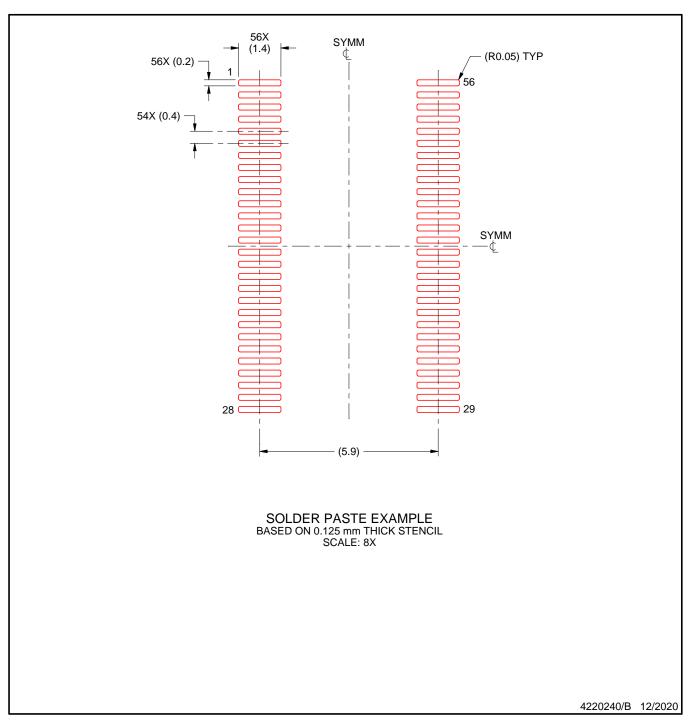
NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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